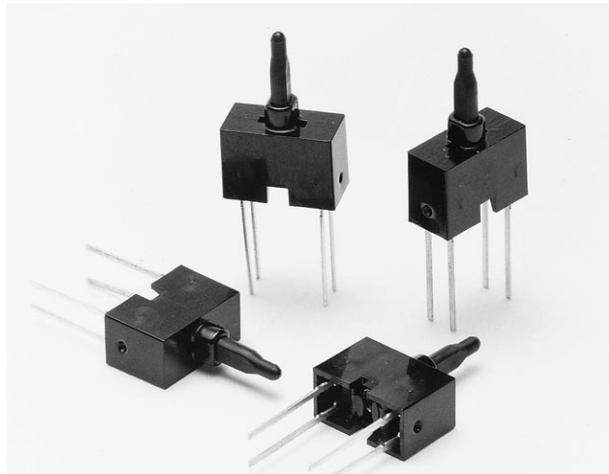
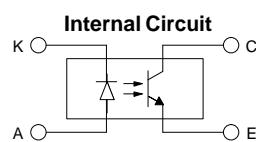
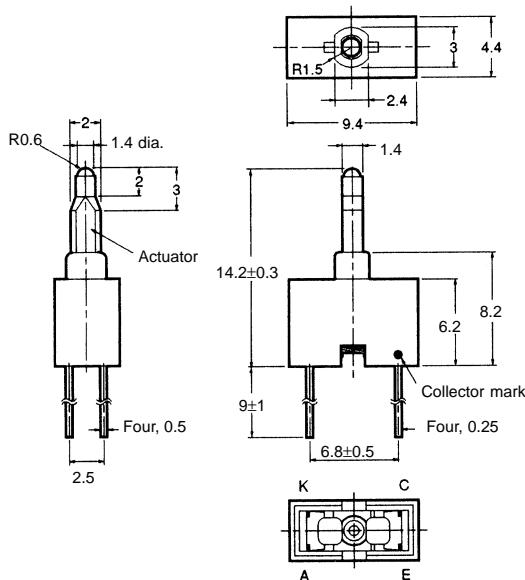


**Actuator**

- Phototransistor output.
- Incorporates built-in actuator.
- Small size allows use in confined spaces.
- No mechanical contacts ensure long life expectancy.
- Low operating force (15gf (0.15N)).

**Dimensions**

Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.3
3 < mm ≤ 6	±0.375
6 < mm ≤ 10	±0.45
10 < mm ≤ 18	±0.55
18 < mm ≤ 30	±0.65

**Specifications****■ Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )**

Item		Symbol	Rated value
Emitter	Forward current	$I_F$	50 mA (see note 1)
	Pulse forward current	$I_{FP}$	1 A (see note 2)
	Reverse voltage	$V_R$	4 V
Detector	Collector-Emitter voltage	$V_{CEO}$	30 V
	Emitter-Collector voltage	$V_{ECO}$	5 V
	Collector current	$I_C$	20 mA
	Collector dissipation	$P_C$	100 mW (see note 1)
Ambient temperature	Operating	$T_{opr}$	-25°C to 70°C
	Storage	$T_{stg}$	-40°C to 100°C
	Soldering	$T_{sol}$	260°C

**Note:** 1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.  
2. The pulse width is 10  $\mu\text{s}$  maximum with a frequency of 100 Hz.

## ■ Electrical and Optical Characteristics (Ta = 25°C)

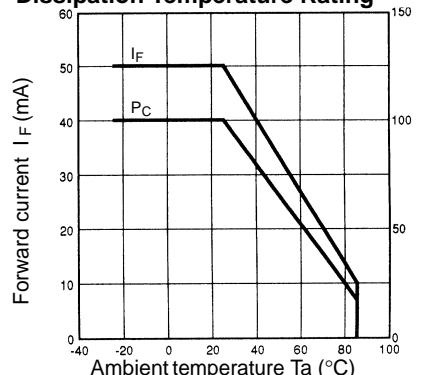
Item		Symbol	Value	Condition
Emitter	Forward voltage	V <sub>F</sub>	1.2 V typ., 1.5 V max.	I <sub>F</sub> = 30 mA
	Reverse current	I <sub>R</sub>	0.01 µA typ., 10 µA max.	V <sub>CE</sub> = 4 V
	Peak emission wavelength	λ <sub>P</sub>	940 nm typ.	I <sub>F</sub> = 20 mA
Detector	Light current	I <sub>L</sub>	0.5 mA min.	I <sub>F</sub> = 20 mA, V <sub>CE</sub> = 5 V at free position (FP)
	Dark current	I <sub>D</sub>	2 nA typ., 200 nA max.	V <sub>CE</sub> = 10 V, 0 °C
	Leakage current	I <sub>LEAK</sub>	10 µA max.	I <sub>F</sub> = 20 mA, V <sub>CE</sub> = 5 V at operating position (OP)
	Collector-Emitter saturated voltage	V <sub>CE</sub> (sat)	0.15 V typ., 0.4 V max.	I <sub>F</sub> = 20 mA, I <sub>L</sub> = 0.1 mA
	Peak spectral sensitivity wavelength	λ <sub>P</sub>	850 nm typ.	V <sub>CE</sub> = 10 V
Rising time	tr	---	---	---
Falling time	tf	---	---	---

## ■ Mechanical Characteristics

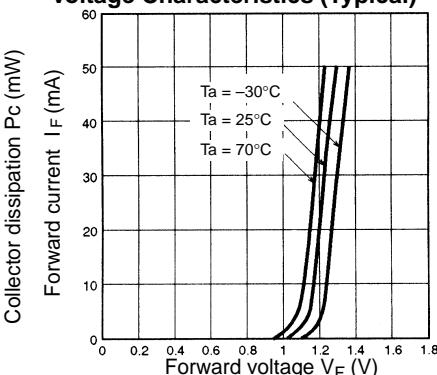
Actuator operation (I <sub>F</sub> = 20 mA, V <sub>CE</sub> = 5 V) (see note 1)	Free position (FP): 14.2±0.3 mm Operating position (OP): 13.0 mm min. Total travel position (TTP): 12.1 mm max.
Operating force (see note 2)	15 gf (0.15 N) max.
Mechanical life expectancy	500,000 operations min. (The actuator traveling from its FP to OP via TTP is regarded as one operation.)

## Engineering Data

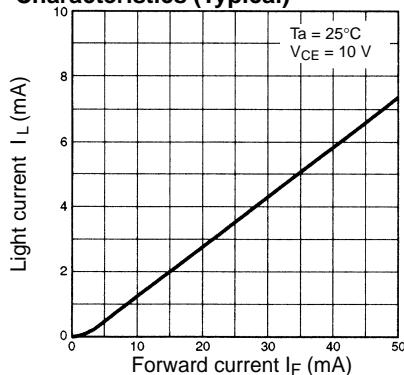
Forward Current vs. Collector Dissipation Temperature Rating



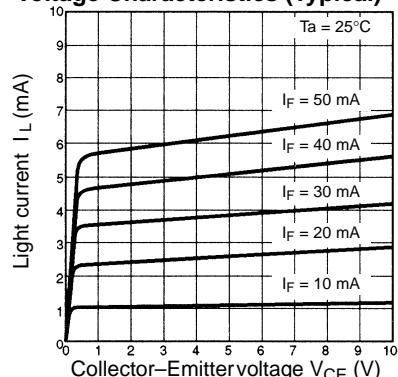
Forward Current vs. Forward Voltage Characteristics (Typical)



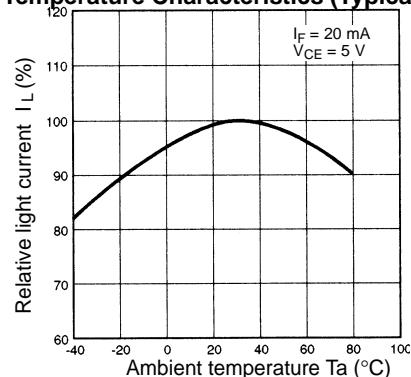
Light Current vs. Forward Current Characteristics (Typical)



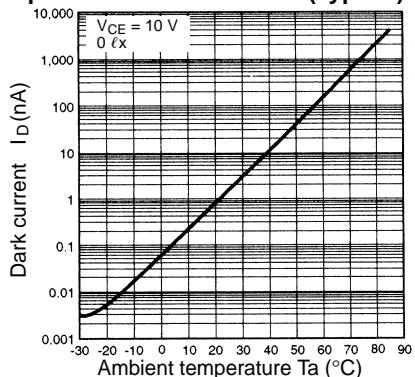
Light Current vs. Collector-Emitter Voltage Characteristics (Typical)



Relative Light Current vs. Ambient Temperature Characteristics (Typical)



Dark Current vs. Ambient Temperature Characteristics (Typical)



Sensing Position Characteristics (Typical)

